TXU0101-Q1 具有施密特触发输入和三态输出的汽车用 single-bit 定向电压电平转换器

1 特性

- 完全可配置的双电源轨设计允许各个端口在 1.1V 至 5.5V 范围内运行
- 在 3.3V 至 5.0V 范围内，支持高达 200Mbps 的速率
- 施密特触发输入可实现慢速和高噪声输入
- 带集成静态下拉电阻器的输入阻止通道流动
- 高驱动强度（在 5V 时最高达 12mA）
- 低功耗
  - 最大值 2.5μA (25°C)
  - 最大值 6μA（-40°C 至 125°C）
- V_{CC} 隔离和 V_{CC} 断开 ($I_{off-float}$) 特性
  - 如果任何一个 V_{CC} 输入低于 100mV 或已断开，则所有输出均禁用且处于高阻抗状态
- I_{off} 支持局部断电模式运行
- 带有 $V_{CC(MIN)}$ 电路的控制逻辑 (OE) 允许从端口 A 或 B 进行控制
- 引脚排列兼容 TXB 系列电平转换器
- 工作温度范围为 –40°C 至 +125°C
- 闩锁性能超过 100 mA，符合 JESD 78 II 类规范的要求
- ESD 保护性能超过 JESD 22 规范要求
  - 2500V 人体放电模型
  - 1500V 充电器件模型

2 应用

- 消除缓慢或嘈杂输入信号
- 驱动指示 LED 或蜂鸣器
- 机械开关去抖
- 通用 I/O 电平转换
- 推挽电平转换（UART、SPI、JTAG 等等）

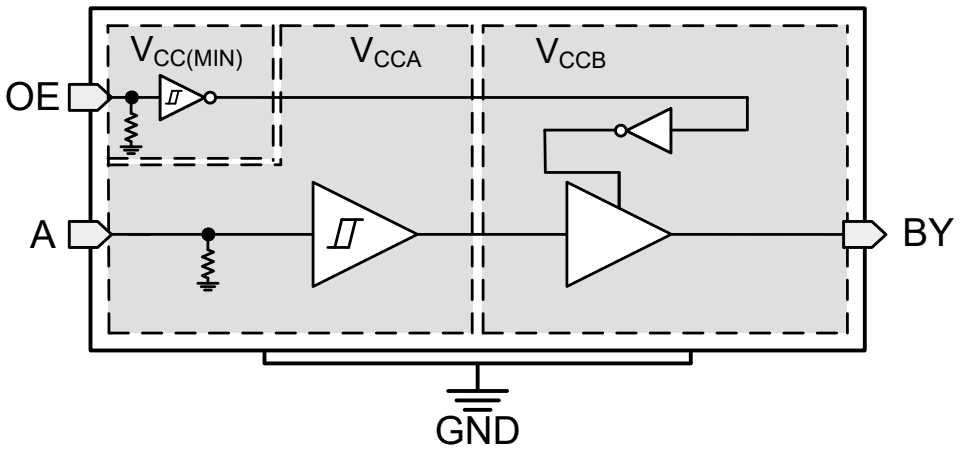
3 说明

TXU0101-Q1 是一款 1 位双电源同相定向电压电平转换器件。A 引脚以 V_{CCA} 逻辑电平为基准，OE 引脚可以 V_{CCA} 或 V_{CCB} 逻辑电平为基准，B 引脚以 V_{CCB} 逻辑电平为基准。A 端口可以接受 1.1V 至 5.5V 的输入电压，而 B 端口也可接受 1.1V 至 5.5V 的输入电压。如果 OE 相对于任一电源设为高电平，可能会发生从 A 到 B 的定向数据传输。OE 设为低电平时，所有输出引脚均处于高阻抗状态。请参阅*器件功能模式*，简要了解控制逻辑的运行。

封装信息(1)

器件型号	封装	封装尺寸（标称值）
TXU0101	SC70 (DCK) (6)	2.00mm × 1.25mm
	SOT-5X3 (DRL) (6)(2)	1.60mm × 1.20mm
	SON (DRY) (6)	1.45mm × 1.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。
(2) 预发布封装。



TXU0101-Q1 功能方框图

本文档旨在为方便起见，提供有关 TI 产品中文版本的信息，以确认产品的概要。有关适用的官方英文版本的最新信息，请访问 www.ti.com，其内容始终优先。TI 不保证翻译的准确性和有效性。在实际设计之前，请务必参考最新版本的英文版本。

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4 Revision History

DATE	REVISION	NOTES
August 2022	*	Initial Release

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5 Pin Configuration and Functions—TXU0101-Q1

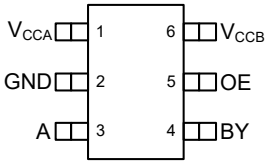


图 5-1. DCK Package, 6-Pin SC70 Transparent (Top View)

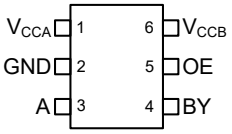


图 5-2. DRL Package (Preview), 6-Pin SOT-5X3 Transparent (Top View)

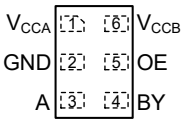


图 5-3. DRY Package, 6-Pin SON Transparent (Top View)

表 5-1. TXU0101 Pin Functions

PIN		TYPE(1)	DESCRIPTION
NAME	NO.		
V_{CCA}	1	—	A-port supply voltage. 1.1 V ⩽ V_{CCA} ⩽ 5.5 V
GND	2	—	Ground
A	3	I	Input A. Referenced to V_{CCA}.
BY	4	O	Output B. Referenced to V_{CCB}.
OE	5	I	Output Enable. Pull to GND to place all outputs in high-impedance mode. Pull to V_{CCA} or V_{CCB} to enable all outputs.
V_{CCB}	6	—	B-port supply voltage. 1.1 V ⩽ V_{CCB} ⩽ 5.5 V

(1) I = input, O = output

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CCA}	Supply voltage A		– 0.5	6.5	V
V_{CCB}	Supply voltage B		– 0.5	6.5	V
V_I	Input Voltage(2)	I/O Ports (A Port)	– 0.5	6.5	V
		I/O Ports (B Port)	– 0.5	6.5	
		OE	– 0.5	6.5	
V_O	Voltage applied to any output in the high-impedance or power-off state(2)	A Port	– 0.5	6.5	V
		B Port	– 0.5	6.5	
V_O	Voltage applied to any output in the high or low state(2) (3)	A Port	– 0.5	V_{CCA} + 0.5	V
		B Port	– 0.5	V_{CCB} + 0.5	
I_{IK}	Input clamp current	V_I < 0	– 20		mA
I_{OK}	Output clamp current	V_O < 0	– 20		mA
I_O	Continuous output current		– 25	25	mA
	Continuous current through V_{CC} or GND		– 100	100	mA
T_j	Junction Temperature			150	°C
T_{stg}	Storage temperature		– 65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*.. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
(3) The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 (1)	±2500	V
		Charged device model (CDM), per AEC Q100-011	±1500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

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6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) (1) (2) (3)

			MIN	MAX	UNIT
V_{CCA}	Supply voltage A		1.08	5.5	V
V_{CCB}	Supply voltage B		1.08	5.5	V
I_{OH}	High-level output current	V_{CCO} = 1.1 V		–1.5	mA
		V_{CCO} = 1.4 V		–3	
		V_{CCO} = 1.65 V		–4.5	
		V_{CCO} = 2.3 V		–8	
		V_{CCO} = 3 V		–10	
		V_{CCO} = 4.5 V		–12	
I_{OL}	Low-level output current	V_{CCO} = 1.1 V		1.5	mA
		V_{CCO} = 1.4 V		3	
		V_{CCO} = 1.65 V		4.5	
		V_{CCO} = 2.3 V		8	
		V_{CCO} = 3 V		10	
		V_{CCO} = 4.5 V		12	
V_I	Input voltage (3)		0	5.5	V
V_O	Output voltage	Active State	0	V_{CCO}	V
		Tri-State	0	5.5	
T_A	Operating free-air temperature		–40	125	°C

(1) V_{CCI} is the V_{CC} associated with the input port.
(2) V_{CCO} is the V_{CC} associated with the output port.
(3) All control inputs and data I/Os of this device have weak pulldowns to ensure the line is not floating when undefined external to the device. The input leakage from these weak pulldowns is defined by the I_I specification indicated under *Electrical Characteristics*.

6.4 Thermal Information

THERMAL METRIC(1)		TXU0101-Q1			UNIT
		DCK (SC70)	DRL (SOT-5X3)	DRY (SON)	
		8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	215.9	TBD	279.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	143.2	TBD	172.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	76.6	TBD	154.6	°C/W
Y_{JT}	Junction-to-top characterization parameter	58.6	TBD	22.1	°C/W
Y_{JB}	Junction-to-board characterization parameter	76.2	TBD	153.8	°C/W
$R_{\theta JC(bottom)}$	Junction-to-case (bottom) thermal resistance	N/A	TBD	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

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6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)(1) (2)

PARAMETER		TEST CONDITIONS	V_{CCA}	V_{CCB}	Operating free-air temperature (T_A)									UNIT
					25°C			– 40°C to 85°C			– 40°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{T+}	Positive-going input-threshold voltage	Data Inputs (Ax, Bx) (Referenced to V_{CCI})	1.1 V	1.1 V				0.44		0.88	0.44		0.88	V
			1.4 V	1.4 V				0.60		0.98	0.60		0.98	
			1.65 V	1.65 V				0.76		1.13	0.76		1.13	
			2.3 V	2.3 V				1.08		1.56	1.08		1.56	
			3 V	3 V				1.48		1.92	1.48		1.92	
			4.5 V	4.5 V				2.19		2.74	2.19		2.74	
			5.5 V	5.5 V				2.65		3.33	2.65		3.33	
		OE (Referenced to V_{CCA} or V_{CCB})	1.1 V	1.1 V				0.44		0.88	0.44		0.88	V
			1.4 V	1.4 V				0.60		0.98	0.60		0.98	
			1.65 V	1.65 V				0.76		1.13	0.76		1.13	
			2.3 V	2.3 V				1.08		1.56	1.08		1.56	
			3 V	3 V				1.48		1.92	1.48		1.92	
			4.5 V	4.5 V				2.19		2.74	2.19		2.74	
			5.5 V	5.5 V				2.65		3.33	2.65		3.33	
V_{T-}	Negative-going input-threshold voltage	Data Inputs (Ax, Bx) (Referenced to V_{CCI})	1.1 V	1.1 V				0.17		0.48	0.17		0.48	V
			1.4 V	1.4 V				0.28		0.59	0.28		0.59	
			1.65 V	1.65 V				0.35		0.69	0.35		0.69	
			2.3 V	2.3 V				0.56		0.97	0.56		0.97	
			3 V	3 V				0.89		1.5	0.89		1.5	
			4.5 V	4.5 V				1.51		1.97	1.51		1.97	
			5.5 V	5.5 V				1.88		2.4	1.88		2.4	
		OE (Referenced to V_{CCA} or V_{CCB})	1.1 V	1.1 V				0.17		0.48	0.17		0.48	V
			1.4 V	1.4 V				0.28		0.59	0.28		0.59	
			1.65 V	1.65 V				0.35		0.69	0.35		0.69	
			2.3 V	2.3 V				0.56		0.97	0.56		0.97	
			3 V	3 V				0.89		1.5	0.89		1.5	
			4.5 V	4.5 V				1.51		1.97	1.51		1.97	
			5.5 V	5.5 V				1.88		2.46	1.88		2.46	
ΔV_T	Input-threshold hysteresis (V_{T+} – V_{T-})	Data Inputs (Ax, Bx) (Referenced to V_{CCI})	1.1 V	1.1 V				0.2		0.4	0.2		0.4	V
			1.4 V	1.4 V				0.25		0.5	0.25		0.5	
			1.65 V	1.65 V				0.3		0.55	0.3		0.55	
			2.3 V	2.3 V				0.38		0.65	0.38		0.65	
			3 V	3 V				0.46		0.72	0.46		0.72	
			4.5 V	4.5 V				0.58		0.93	0.58		0.93	
			5.5 V	5.5 V				0.69		1.06	0.69		1.06	
		OE (Referenced to V_{CCA} or V_{CCB})	1.1 V	1.1 V				0.15		0.41	0.15		0.41	V
			1.4 V	1.4 V				0.2		0.5	0.2		0.5	
			1.65 V	1.65 V				0.23		0.55	0.23		0.55	
			2.3 V	2.3 V				0.32		0.65	0.32		0.65	
			3 V	3 V				0.39		0.72	0.39		0.72	
			4.5 V	4.5 V				0.57		0.97	0.57		0.97	
			5.5 V	5.5 V				0.69		1.18	0.69		1.18	

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6.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)(1) (2)

PARAMETER		TEST CONDITIONS	V_{CCA}	V_{CCB}	Operating free-air temperature (T_A)									UNIT
					25°C			– 40°C to 85°C			– 40°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{OH}	High-level output voltage (3)	I_{OH} = – 0.1 mA	1.1 V – 5.5 V	1.1 V – 5.5 V				V_{CCO} – 0.1			V_{CCO} – 0.1			V
		I_{OH} = – 0.5 mA	1.1 V	1.1 V				0.82			0.82			
		I_{OH} = – 3 mA	1.4 V	1.4 V				1			1			
		I_{OH} = – 4.5 mA	1.65 V	1.65 V				1.2			1.2			
		I_{OH} = – 8 mA	2.3 V	2.3 V				1.7			1.7			
		I_{OH} = – 10 mA	3 V	3 V				2.2			2.2			
		I_{OH} = – 12 mA	4.5 V	4.5 V				3.7			3.7			
V_{OL}	Low-level output voltage (4)	I_{OL} = 0.1 mA	1.1 V – 5.5 V	1.1 V – 5.5 V						0.1			0.1	V
		I_{OL} = 0.5 mA	1.1 V	1.1 V						0.27			0.27	
		I_{OL} = 3 mA	1.4 V	1.4 V						0.35			0.35	
		I_{OL} = 4.5 mA	1.65 V	1.65 V						0.45			0.45	
		I_{OL} = 8 mA	2.3 V	2.3 V						0.7			0.7	
		I_{OL} = 10 mA	3 V	3 V						0.8			0.8	
		I_{OL} = 8 mA	4.5 V	4.5 V						0.55			0.55	
		I_{OL} = 12 mA	4.5 V	4.5 V						0.8			0.8	
I_I	Input leakage current	OE V_I = V_{CC} or GND	1.1 V – 5.5 V	1.1 V – 5.5 V	– 0.1		1.5	– 0.1		1.5	– 0.1		2	µA
		Data Inputs (Ax, Bx) V_I = V_{CCI} or GND	1.1 V – 5.5 V	1.1 V – 5.5 V	– 0.1		1.5	– 0.1		1.5	– 2		2	µA
I_{off}	Partial power down current	A Port or B Port V_I or V_O = 0 V – 5.5 V	0 V	1.1 V – 5.5 V	– 1.5		1.5	– 2		2	– 2.5		2.5	µA
			1.1 V – 5.5 V	0 V	– 1.5		1.5	– 2		2	– 2.5		2.5	
$I_{off-float}$	Floating supply Partial power down current	A Port or B Port V_I or V_O = GND	Floating(5)	1.1 V – 5.5 V	– 1.5		1.5	– 2		2	– 2.5		2.5	µA
			0 V – 5.5 V	Floating(5)	– 1.5		1.5	– 2		2	– 2.5		2.5	
I_{OZ}	Tri-state output current	A or B Port: V_I = V_{CCI} or GND V_O = V_{CCO} or GND OE = GND	1.1 V – 5.5 V	1.1 V – 5.5 V	– 0.3		0.3	– 1		1	– 2		2	µA
I_{CCA}	V_{CCA} supply current	V_I = V_{CCI} or GND I_O = 0	1.1 V – 5.5 V	1.1 V – 5.5 V			1.5			2.5			6	µA
			0 V	5.5 V	– 0.3			– 1			– 1			
			5.5 V	0 V			1			1.5			3	
		V_I = GND I_O = 0	5.5 V	Floating(5)			1.5			7			15	
I_{CCB}	V_{CCB} supply current	V_I = V_{CCI} or GND I_O = 0	1.1 V – 5.5 V	1.1 V – 5.5 V			1.5			2.5			6	µA
			0 V	5.5 V			1			1.5			3	
			5.5 V	0 V	– 0.3			– 1			– 1			
		V_I = GND I_O = 0	Floating(5)	5.5 V			1.5			7			15	

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6.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)(1) (2)

PARAMETER		TEST CONDITIONS	V_{CCA}	V_{CCB}	Operating free-air temperature (T_A)									UNIT
					25°C			– 40°C to 85°C			– 40°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
I_{CCA} + I_{CCB}	Combined supply current	V_I = V_{CCI} or GND I_O = 0	1.1 V – 5.5 V	1.1 V – 5.5 V			2.5			3			6	µA
C_i	Control Input Capacitance	V_I = 3.3 V or GND	3.3 V	3.3 V		2.75			3			3.5		pF
C_{io}	Data I/O Capacitance	OE = GND, V_O = 1.65 V DC +1 MHz −16 dBm sine wave	3.3 V	3.3 V		3			4			4		pF

(1) V_{CCI} is the V_{CC} associated with the input port.
(2) V_{CCO} is the V_{CC} associated with the output port.
(3) Tested at V_I = $V_{T+(MAX)}$.
(4) Tested at V_I = $V_{T-(MIN)}$.
(5) Floating is defined as a node that is both not actively driven by an external device and has leakage not exeeding 10 nA.

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6.6 Switching Characteristics, V_{CCA} = 1.2 ± 0.1 V

See 图 7-1 and 表 7-1 for test circuit and loading. See 图 7-2, 图 7-3, and 图 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})														UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	3.3		96	0.5		43	0.5		37	0.5		32	0.5		30	0.5		31	ns
				−40°C to 125°C	3.3		96	0.5		43	0.5		37	0.5		32	0.5		30	0.5		31	
		B	A	−40°C to 85°C	3.3		95	1.9		80	0.5		75	0.5		70	0.5		69	0.5		69	
				−40°C to 125°C	3.3		95	1.9		80	0.5		75	0.5		70	0.5		69	0.5		69	
t_{dis}	Disable time	OE	A	−40°C to 85°C	28.8		133	28.5		130	28.4		133	28.8		137	28.4		143	18.7		211	ns
				−40°C to 125°C	28.8		133	28.5		130	28.4		133	28.8		137	28.4		143	18.7		211	
		OE	B	−40°C to 85°C	32.5		150	27.6		117	25.8		110	22.5		104	22.1		112	20.1		181	
				−40°C to 125°C	32.5		150	27.6		117	25.8		110	22.5		104	22.1		112	20.1		181	
t_{en}	Enable time	OE	A	−40°C to 85°C	24.1		237	22.1		229	21.4		230	21.3		232	21.7		235	22.7		244	ns
				−40°C to 125°C	24.1		237	22.1		229	21.4		230	21.3		232	21.7		235	22.7		244	
		OE	B	−40°C to 85°C	21.3		237	14.3		152	11.2		140	8.8		130	8.2		130	8.4		132	
				−40°C to 125°C	21.3		237	14.3		152	11.2		140	8.8		130	8.2		130	8.4		132	

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6.7 Switching Characteristics, V_{CCA} = 1.5 ± 0.1 V

See 图 7-1 and 表 7-1 for test circuit and loading. See 图 7-2, 图 7-3, and 图 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})																		UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	1.9		80	0.5		31	0.5		25	0.5		19	0.5		17	0.5		15	ns
				−40°C to 125°C	1.9		80	0.5		31	0.5		25	0.5		20	0.5		18	0.5		16	
		B	A	−40°C to 85°C	0.5		43	0.5		31	0.5		28	0.5		26	0.5		25	0.5		24	
				−40°C to 125°C	0.5		43	0.5		31	0.5		28	0.5		26	0.5		25	0.5		24	
t_{dis}	Disable time	OE	A	−40°C to 85°C	20.0		91	19.0		82	18.8		81	19.2		82	19.6		83	12.2		90	ns
				−40°C to 125°C	20.0		95	19.0		86	18.8		85	19.2		87	19.6		88	12.2		92	
		OE	B	−40°C to 85°C	27.4		127	21.7		91	19.9		82	16.3		71	15.9		71	13.7		70	
				−40°C to 125°C	27.4		127	21.7		95	19.9		86	16.3		75	15.9		75	13.7		74	
t_{en}	Enable time	OE	A	−40°C to 85°C	14.9		102	14.4		86	13.5		88	12.7		90	12.6		92	13.2		97	ns
				−40°C to 125°C	14.9		102	14.4		89	13.5		91	12.7		93	12.6		96	13.2		100	
		OE	B	−40°C to 85°C	17.9		175	12.7		80	9.1		69	6.1		57	4.9		53	4.5		54	
				−40°C to 125°C	17.9		175	12.7		81	9.1		71	6.1		60	4.9		56	4.5		57	

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6.8 Switching Characteristics, V_{CCA} = 1.8 ± 0.15 V

See 图 7-1 and 表 7-1 for test circuit and loading. See 图 7-2, 图 7-3, and 图 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})														UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	0.5		75	0.5		28	0.5		22	0.5		17	0.5		14	0.5		12	ns
				−40°C to 125°C	0.5		75	0.5		28	0.5		23	0.5		17	0.5		15	0.5		13	
		B	A	−40°C to 85°C	0.5		37	0.5		25	0.5		22	0.5		19	0.5		19	0.5		18	
				−40°C to 125°C	0.5		37	0.5		25	0.5		23	0.5		20	0.5		19	0.5		19	
t_{dis}	Disable time	OE	A	−40°C to 85°C	17.2		79	14.7		67	14.5		65	14.3		65	14.4		66	8.5		71	ns
				−40°C to 125°C	17.2		83	14.7		71	14.5		69	14.3		70	14.4		71	8.5		75	
		OE	B	−40°C to 85°C	25.4		121	18.7		81	16.5		71	12.8		60	12.5		58	9.8		55	
				−40°C to 125°C	25.4		123	18.7		86	16.5		76	12.8		64	12.5		62	9.8		59	
t_{en}	Enable time	OE	A	−40°C to 85°C	10.9		88	9.5		66	9.4		63	8.6		65	8.2		66	8.1		69	ns
				−40°C to 125°C	10.9		88	9.5		69	9.4		67	8.6		68	8.2		70	8.1		73	
		OE	B	−40°C to 85°C	16.7		177	10.4		75	8.1		58	4.9		46	3.3		42	2.2		39	
				−40°C to 125°C	16.7		177	10.4		77	8.1		60	4.9		49	3.3		44	2.2		42	

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6.9 Switching Characteristics, V_{CCA} = 2.5 ± 0.2 V

See 图 7-1 and 表 7-1 for test circuit and loading. See 图 7-2, 图 7-3, and 图 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})																		UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	0.5		70	0.5		26	0.5		20	0.5		14	0.5		12	0.5		9	ns
				−40°C to 125°C	0.5		70	0.5		26	0.5		20	0.5		14	0.5		12	0.5		10	
		B	A	−40°C to 85°C	0.5		32	0.5		19	0.5		17	0.5		14	0.5		13	0.5		13	
				−40°C to 125°C	0.5		32	0.5		20	0.5		17	0.5		14	0.5		13	0.5		13	
t_{dis}	Disable time	OE	A	−40°C to 85°C	12.9		65	10.5		51	9.0		51	8.1		43	8.4		44	5.0		45	ns
				−40°C to 125°C	12.9		68	10.5		55	9.0		50	8.1		47	8.4		48	5.0		49	
		OE	B	−40°C to 85°C	23.2		112	16.5		74	14.0		61	9.0		46	9.1		44	6.4		39	
				−40°C to 125°C	23.2		115	16.5		79	14.0		66	9.0		51	9.1		48	6.4		43	
t_{en}	Enable time	OE	A	−40°C to 85°C	7.9		80	5.9		50	5.1		44	4.7		39	4.4		40	3.7		41	ns
				−40°C to 125°C	7.9		80	5.9		53	5.1		47	4.7		42	4.4		43	3.7		44	
		OE	B	−40°C to 85°C	16.3		183	9.2		74	6.0		54	4.0		36	2.1		31	0.5		27	
				−40°C to 125°C	16.3		183	9.2		76	6.0		57	4.0		38	2.1		33	0.5		29	

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6.10 Switching Characteristics, V_{CCA} = 3.3 ± 0.3 V

See 图 7-1 and 表 7-1 for test circuit and loading. See 图 7-2, 图 7-3, and 图 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})														UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	0.5		69	0.5		25	0.5		19	0.5		13	0.5		11	0.5		8	ns
				−40°C to 125°C	0.5		69	0.5		25	0.5		19	0.5		13	0.5		11	0.5		9	
		B	A	−40°C to 85°C	0.5		30	0.5		17	0.5		14	0.5		12	0.5		11	0.5		10	
				−40°C to 125°C	0.5		30	0.5		18	0.5		15	0.5		12	0.5		11	0.5		10	
t_{dis}	Disable time	OE	A	−40°C to 85°C	12.9		62	10.1		47	8.7		42	6.9		39	6.6		39	6.9		40	ns
				−40°C to 125°C	12.9		65	10.1		51	8.7		46	6.9		40	6.6		40	6.9		40	
		OE	B	−40°C to 85°C	22.7		109	15.7		71	13.2		59	8.5		42	7.6		40	4.7		36	
				−40°C to 125°C	22.7		111	15.7		75	13.2		63	8.5		46	7.6		43	4.7		36	
t_{en}	Enable time	OE	A	−40°C to 85°C	6.6		85	4.2		45	3.0		37	2.4		31	2.2		30	1.7		30	ns
				−40°C to 125°C	6.6		85	4.2		47	3.0		40	2.4		33	2.2		32	1.7		33	
		OE	B	−40°C to 85°C	16.3		192	8.9		76	5.4		55	2.6		34	1.8		27	0.5		22	
				−40°C to 125°C	16.3		192	8.9		78	5.4		57	2.6		36	1.8		29	0.5		24	

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6.11 Switching Characteristics, V_{CCA} = 5.0 ± 0.5 V

See 图 7-1 and 表 7-1 for test circuit and loading. See 图 7-2, 图 7-3, and 图 7-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V_{CCB})														UNIT
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V			5.0 ± 0.5 V			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{pd}	Propagation delay	A	B	−40°C to 85°C	0.5		69	0.5		24	0.5		18	0.5		13	0.5		10	0.5		8	ns
				−40°C to 125°C	0.5		69	0.5		24	0.5		19	0.5		13	0.5		11	0.5		8	
		B	A	−40°C to 85°C	0.5		31	0.5		15	0.5		12	0.5		9	0.5		8	0.5		8	
				−40°C to 125°C	0.5		31	0.5		16	0.5		13	0.5		10	0.5		9	0.5		8	
t_{dis}	Disable time	OE	A	−40°C to 85°C	10.8		60	7.7		42	5.9		38	4.2		31	3.4		31	2.8		30	ns
				−40°C to 125°C	10.8		62	7.7		46	5.9		40	4.2		33	3.4		33	2.8		32	
		OE	B	−40°C to 85°C	9.7		109	5.9		69	13.2		56	8.4		40	6.9		37	3.7		30	
				−40°C to 125°C	9.7		111	5.9		73	13.2		60	8.4		43	6.9		39	3.7		33	
t_{en}	Enable time	OE	A	−40°C to 85°C	6.0		102	2.8		44	1.2		33	0.5		25	0.5		22	0.5		21	ns
				−40°C to 125°C	6.0		102	2.8		46	1.2		36	0.5		27	0.5		24	0.5		23	
		OE	B	−40°C to 85°C	16.7		212	8.8		82	4.8		58	1.6		35	0.5		26	0.5		19	
				−40°C to 125°C	16.7		212	8.8		83	4.8		60	1.6		37	0.5		28	0.5		21	

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6.12 Operating Characteristics

T_A = 25℃ (1)

PARAMETER		Test Conditions	Supply Voltage (V_{CCB} = V_{CCA})						UNIT
			1.2 ± 0.1 V	1.5 ± 0.1 V	1.8 ± 0.15 V	2.5 ± 0.2 V	3.3 ± 0.3 V	5.0 ± 0.5 V	
			TYP	TYP	TYP	TYP	TYP	TYP	
C_{pdA} (2)	A to B: outputs enabled	A Port CL = 0, RL = Open f = 10 MHz t_{rise} = t_{fall} = 1 ns	2	2	2	2	2	3	pF
	A to B: outputs disabled		2	2	2	2	2	3	
	B to A: outputs enabled		12	12	12	13	13	16	
	B to A: outputs disabled		2	2	2	2	2	3	
C_{pdB} (3)	A to B: outputs enabled	B Port CL = 0, RL = Open f = 10 MHz t_{rise} = t_{fall} = 1 ns	12	12	12	13	13	16	pF
	A to B: outputs disabled		2	2	2	2	2	3	
	B to A: outputs enabled		2	2	2	2	2	3	
	B to A: outputs disabled		2	2	2	2	2	3	

(1) See the *CMOS Power Consumption and C_{pd} Calculation* application report for additional information about how power dissipation capacitance affects power consumption.
(2) A-Port power dissipation capacitance per transceiver.
(3) B-Port power dissipation capacitance per transceiver.

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6.13 Typical Characteristics

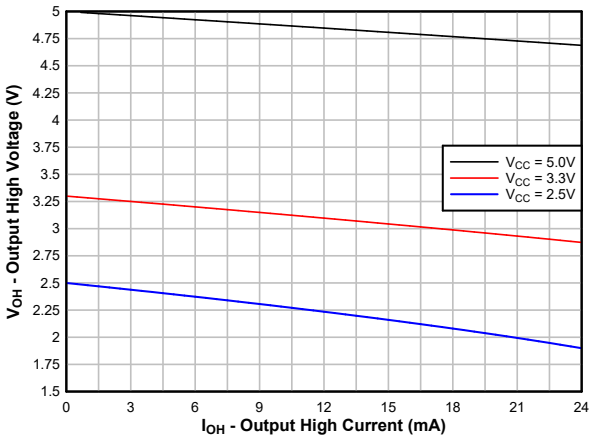


图 6-1. Typical (T_A=25°C) Output High Voltage (V_{OH}) vs Source Current (I_{OH})

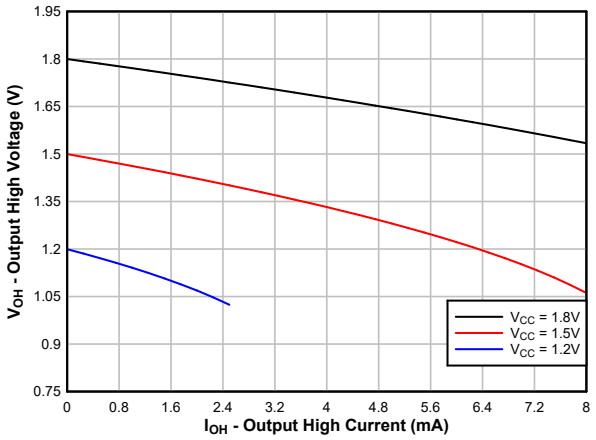


图 6-2. Typical (T_A=25°C) Output High Voltage (V_{OH}) vs Source Current (I_{OH})

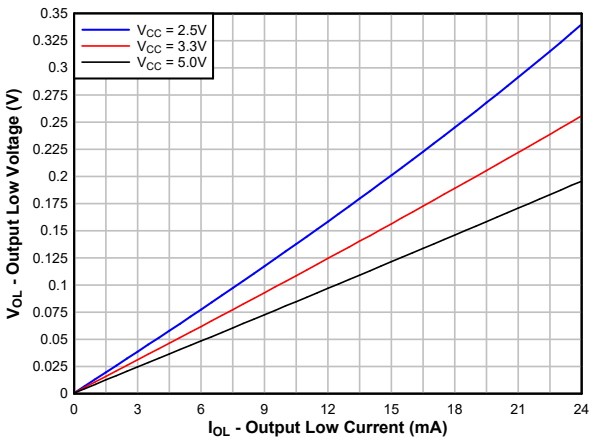


图 6-3. Typical (T_A=25°C) Output Low Voltage (V_{OL}) vs Sink Current (I_{OL})

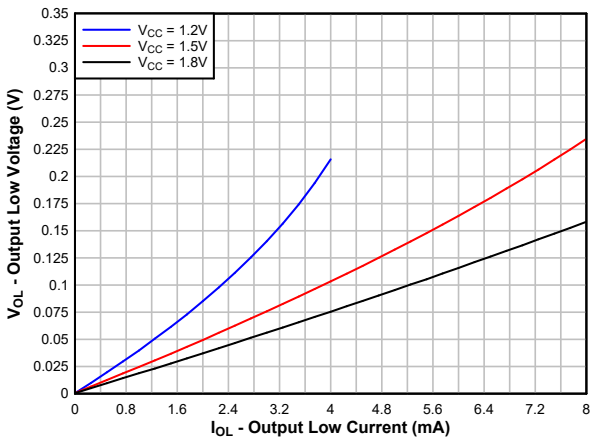


图 6-4. Typical (T_A=25°C) Output Low Voltage (V_{OL}) vs Sink Current (I_{OL})

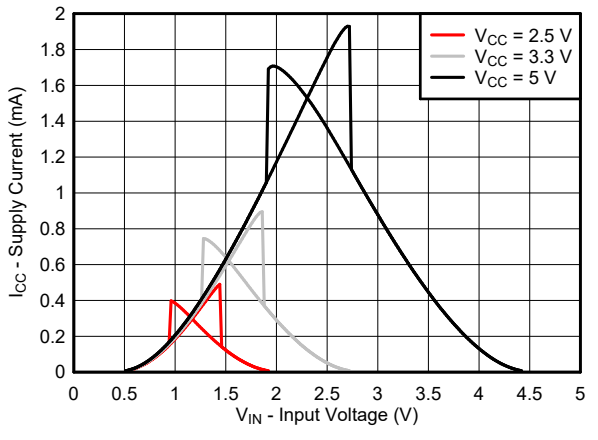


图 6-5. Typical (T_A=25°C) Supply Current (I_{CC}) vs Input Voltage (V_{IN})

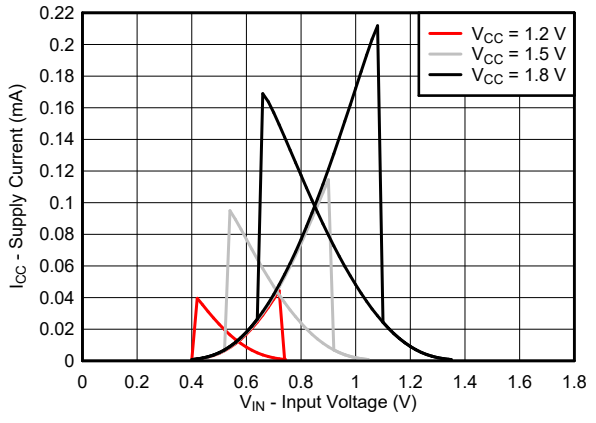


图 6-6. Typical (T_A=25°C) Supply Current (I_{CC}) vs Input Voltage (V_{IN})

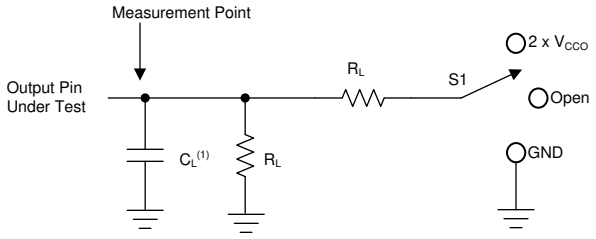
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7 Parameter Measurement Information

7.1 Load Circuit and Voltage Waveforms

Unless otherwise noted, generators supply all input pulses that have the following characteristics:

- f = 1 MHz
- Z_O = 50 Ω
- Δt/ΔV ≤ 1 ns/V

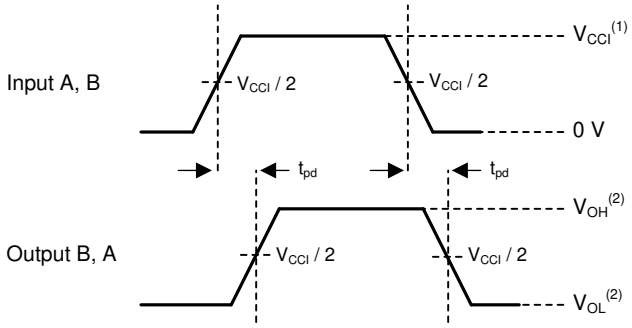


1. C_L includes probe and jig capacitance.

图 7-1. Load Circuit

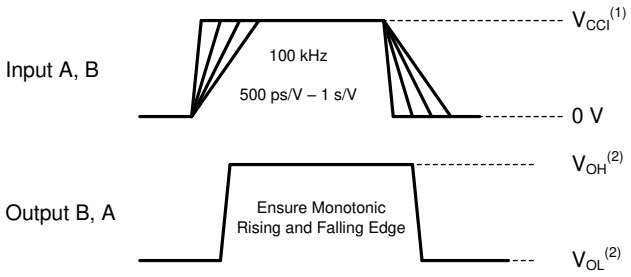
表 7-1. Load Circuit Conditions

Parameter		V_{CCO}	R_L	C_L	S_1	V_{TP}
t_{pd}	Propagation (delay) time	1.1 V – 5.5 V	10 kΩ	5 pF	Open	N/A
t_{en}, t_{dis}	Enable time, disable time	1.1 V – 1.6 V	10 kΩ	5 pF	2 × V_{CCO}	0.1 V
		1.65 V – 2.7 V	10 kΩ	5 pF	2 × V_{CCO}	0.15 V
		3.0 V – 5.5 V	10 kΩ	5 pF	2 × V_{CCO}	0.3 V
t_{en}, t_{dis}	Enable time, disable time	1.1 V – 1.6 V	10 kΩ	5 pF	GND	0.1 V
		1.65 V – 2.7 V	10 kΩ	5 pF	GND	0.15 V
		3.0 V – 5.5 V	10 kΩ	5 pF	GND	0.3 V



1. V_{CCI} is the supply pin associated with the input port.
2. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L, C_L, and S_1

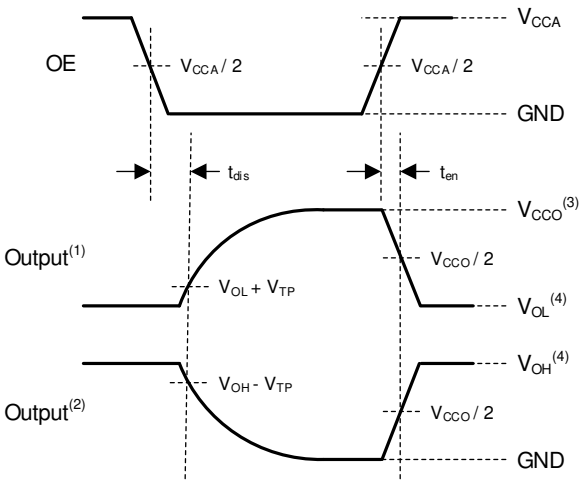
图 7-2. Propagation Delay



1. V_{CCI} is the supply pin associated with the input port.
2. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L, C_L, and S_1

图 7-3. Input Transition Rise and Fall Rate

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1. Output waveform on the condition that input is driven to a valid Logic Low.
2. Output waveform on the condition that input is driven to a valid Logic High.
3. V_{CCO} is the supply pin associated with the output port.
4. V_{OH} and V_{OL} are typical output voltage levels with specified R_L, C_L, and S_1.

图 7-4. Enable Time And Disable Time

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8 Detailed Description

8.1 Overview

The TXU0101-Q1 is a 4-bit translating transceiver that uses two individually configurable power-supply rails. The device is operational with V_{CCA} and V_{CCB} supplies as low as 1.1 V and as high as 5.5 V. Additionally, the device can be operated with V_{CCA} = V_{CCB}. The A port is designed to track V_{CCA}, and the B port is designed to track V_{CCB}.

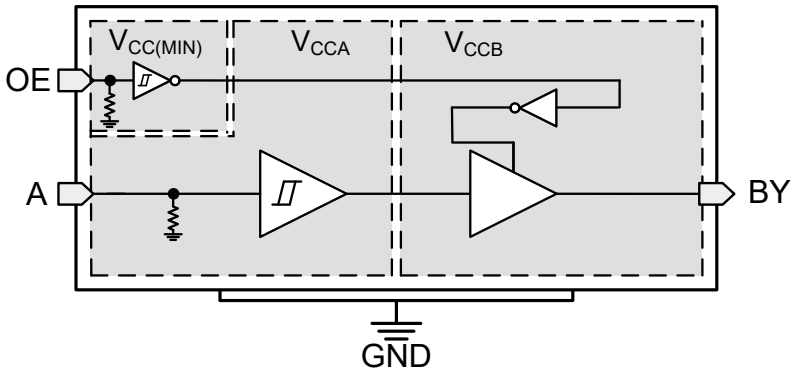
The TXU0101-Q1 device is designed for asynchronous communication between data buses, and transmits data with fixed direction from the A bus to the B bus on some channels and from the B bus to the A bus on the remaining channels. The output-enable input (OE) is used to disable the outputs so the buses are effectively isolated. The output-enable pin of the TXU0101-Q1 (OE) can be referenced to either V_{CCA} or V_{CCB}. The OE pin can be left floating or externally pulled down to ground to ensure the high-impedance state of the level shifter outputs during power up or power down.

This device is fully specified for partial-power-down applications using the I_{off} current. The I_{off} protection circuitry ensures that no excessive current is drawn from or sourced into an input or output while the device is powered down.

The VCC isolation or VCC disconnect feature ensures that if either VCC is less than 100 mV or disconnected with the complementary supply within recommended operating conditions, then the outputs disable and are set to the high-impedance state while the supply current is maintained. The $I_{off-float}$ circuitry ensures that no excessive current is drawn from or sourced into an input or output while the supply is floating.

Glitch-free power supply sequencing allows either supply rail to be powered on or off in any order while providing robust power sequencing performance.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 CMOS Schmitt-Trigger Inputs with Integrated Pulldowns

Standard CMOS inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using ohm's law (R = V ÷ I).

The Schmitt-trigger input architecture provides hysteresis as defined by ΔV_T in the *Electrical Characteristics*, which makes this device extremely tolerant to slow or noisy inputs. Driving the inputs slowly will increase dynamic current consumption of the device. See *Understanding Schmitt Triggers* for additional information regarding Schmitt-trigger inputs.

8.3.1.1 Inputs with Integrated Static Pull-Down Resistors

This device has 5 MΩ typical integrated weak pull-downs for each input. This feature allows all inputs to be left floating without the concern for unstable outputs or increased current consumption. This also helps to reduce external component count for applications where not all channels are used or need to be fixed low. If an external pull-up is required, it should be no larger than 1 MΩ to avoid contention with the 5 MΩ internal pull-down.

8.3.2 Control Logic (OE) with $V_{CC(MIN)}$ Circuitry

The output-enable input (OE) is used to disable the outputs so the buses are effectively isolated. The output-enable pin of the TXU0x04 has $V_{CC(MIN)}$ circuitry, which allows the OE pin to operate with the lower supply voltage. The *Over-Voltage Tolerant Inputs* feature allows the OE pin to operate with the higher supply voltage. This combination means that the enable pin can be referenced to either V_{CCA} or V_{CCB} supply. Multiple permutations of each device are possible since the controller can be placed on either the A or B port and can still control the enable pin.

8.3.3 Balanced High-Drive CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The high drive capability of this device creates fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. The electrical and thermal limits that must be followed at all times are defined in *Absolute Maximum Ratings*.

8.3.4 VCC Isolation and V_{CC} Disconnect

The outputs for this device disable and enter a high-impedance state when either supply is <100 mV or left floating (disconnected), with the complementary supply within the recommended operating conditions. It is recommended to keep the inputs low before floating (disconnecting) either supply.

The $I_{CCx(floating)}$ in the *Electrical Characteristics* specifies the maximum supply current. The $I_{off(float)}$ in the *Electrical Characteristics* specifies the maximum leakage into or out of any input or output pin on the device.

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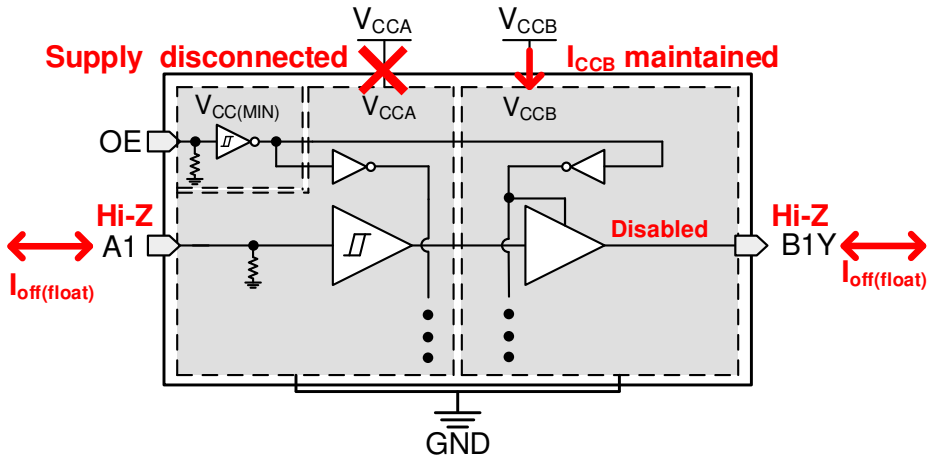


图 8-1. V_{CC} Disconnect Feature

8.3.5 Over-Voltage Tolerant Inputs

Input signals to this device can be driven above the supply voltage as long as they remain below the maximum input voltage value specified in the *Recommended Operating Conditions*.

8.3.6 Glitch-Free Power Supply Sequencing

Either supply rail may be powered on or off in any order without producing a glitch on the inputs or outputs (that is, where the output erroneously transitions to VCC when it should be held low or vice versa). Glitches of this nature can be misinterpreted by a peripheral as a valid data bit, which could trigger a false device reset of the peripheral, a false device configuration of the peripheral, or even a false data initialization by the peripheral.

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8.3.7 Negative Clamping Diodes

图 8-2 shows the inputs and outputs to this device that have negative clamping diodes.

CAUTION

Voltages beyond the values specified in the *Absoulte Maximum Ratings* table can cause damage to the device. The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

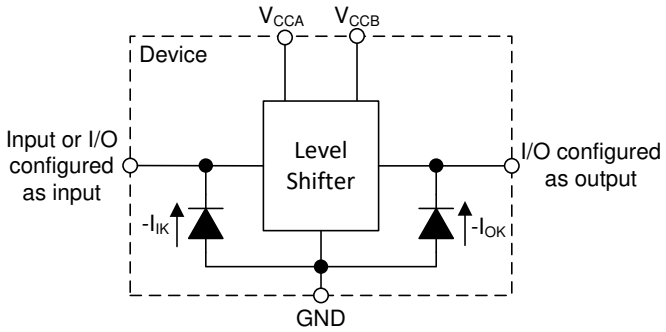


图 8-2. Electrical Placement of Clamping Diodes for Each Input and Output

8.3.8 Fully Configurable Dual-Rail Design

The V_{CCA} and V_{CCB} pins can be supplied at any voltage from 1.1 V to 5.5 V, making the device suitable for translating between any of the voltage nodes (1.2 V, 1.5 V, 1.8 V, 3.3 V, and 5.0 V).

8.3.9 Supports High-Speed Translation

The TXU0101-Q1 device can support high data-rate applications. The translated signal data rate can be up to 200 Mbps when the signal is translated from 3.3 V to 5.0 V.

8.4 Device Functional Modes

表 8-1. Function Table

CONTROL INPUTS	Port Status		OPERATION
OE	Input	Output	
H	L	L	Unidirectional non-inverting voltage translation
H	H	H	Unidirectional non-inverting voltage translation
L	X	Hi-Z	Isolation

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9 Application and Implementation

备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI’s customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The TXU0101-Q1 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The TXU0101-Q1 device is ideal for use in applications where a push-pull driver is connected to the data Inputs. The maximum data rate can be up to 200 Mbps when the device translates a signal from 3.3 V to 5.0 V.

9.2 Typical Application

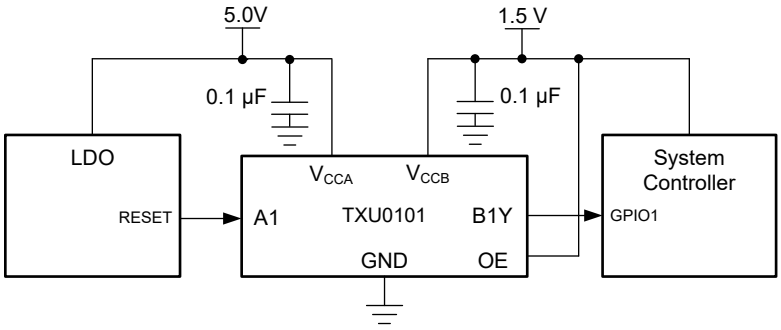


图 9-1. TXU0101-Q1 LDO Reset Application

9.2.1 Design Requirements

Use the parameters listed in 表 9-1 for this design example.

表 9-1. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUES
Input voltage range	1.1 V to 5.5 V
Output voltage range	1.1 V to 5.5 V

9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
  - Use the supply voltage of the device that is driving the TXU0101-Q1 device to determine the input voltage range. For a valid logic-high, the value must exceed the positive-going input-threshold voltage (V_{T+}) of the input port. For a valid logic low the value must be less than the negative-going input-threshold voltage (V_{T-}) of the input port.
- Output voltage range
  - Use the supply voltage of the device that the TXU0101-Q1 device is driving to determine the output voltage range.

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9.2.3 Application Curve

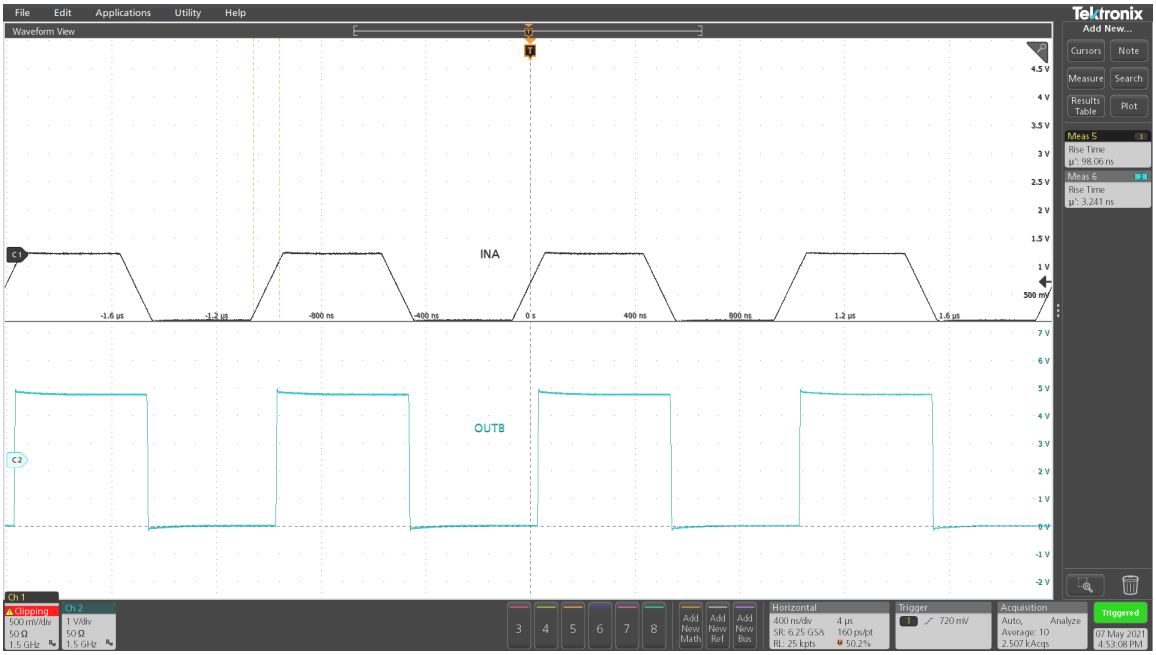


图 9-2. Up Translation at 1 MHz (1.2 V to 5 V)

10 Power Supply Recommendations

Always apply a ground reference to the GND pins first. This device is designed for glitch free power sequencing without any supply sequencing requirements such as ramp order or ramp rate.

Glitch-Free Power Supply Sequencing describes how this device was designed with various power supply sequencing methods in mind to help prevent unintended triggering of downstream devices.

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11 Layout

11.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended:

- Use bypass capacitors on the power supply pins and place them as close to the device as possible. A 0.1 µF capacitor is recommended, but transient performance can be improved by having 1 µF and 0.1 µF capacitors in parallel as bypass capacitors.
- The high drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing.

11.2 Layout Example

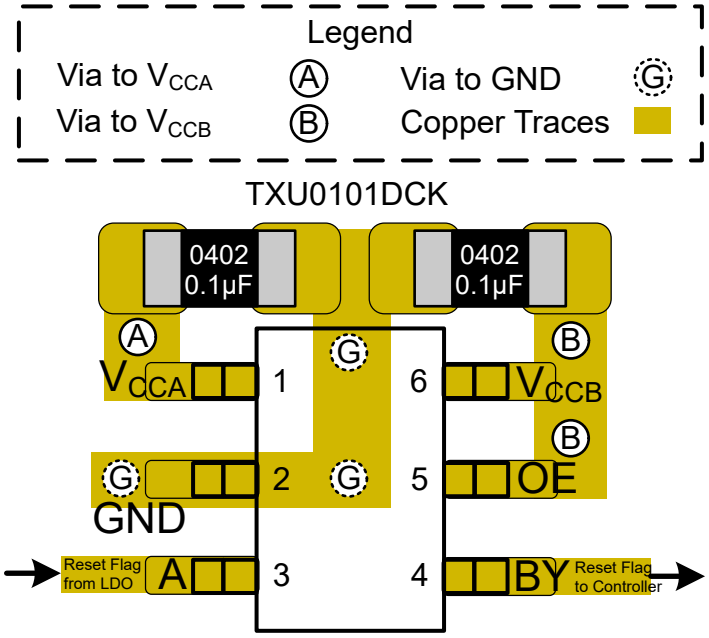


图 11-1. Layout Example – TXU0101-Q1

12 Device and Documentation Support

12.1 Device Support

12.1.1 Regulatory Requirements

No statutory or regulatory requirements apply to this device.

There are no special characteristics for this product.

12.2 Documentation Support

12.2.1 Related Documentation

- Texas Instruments, *Understanding Schmitt Triggers* application report
- Texas Instruments, *CMOS Power Consumption and C_{pd} Calculation* application report

12.3 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*订阅更新*进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

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12.5 Trademarks

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12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 术语表

TI 术语表　　本术语表列出并解释了术语、首字母缩略词和定义。

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TXU0101QDCKRQ1	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	1LR
TXU0101QDCKRQ1.A	Active	Production	SC70 (DCK) | 6	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1LR
TXU0101QDRYRQ1	Active	Production	SON (DRY) | 6	5000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MQ
TXU0101QDRYRQ1.A	Active	Production	SON (DRY) | 6	5000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MQ

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TXU0101-Q1 :

- Catalog : TXU0101

NOTE: Qualified Version Definitions:

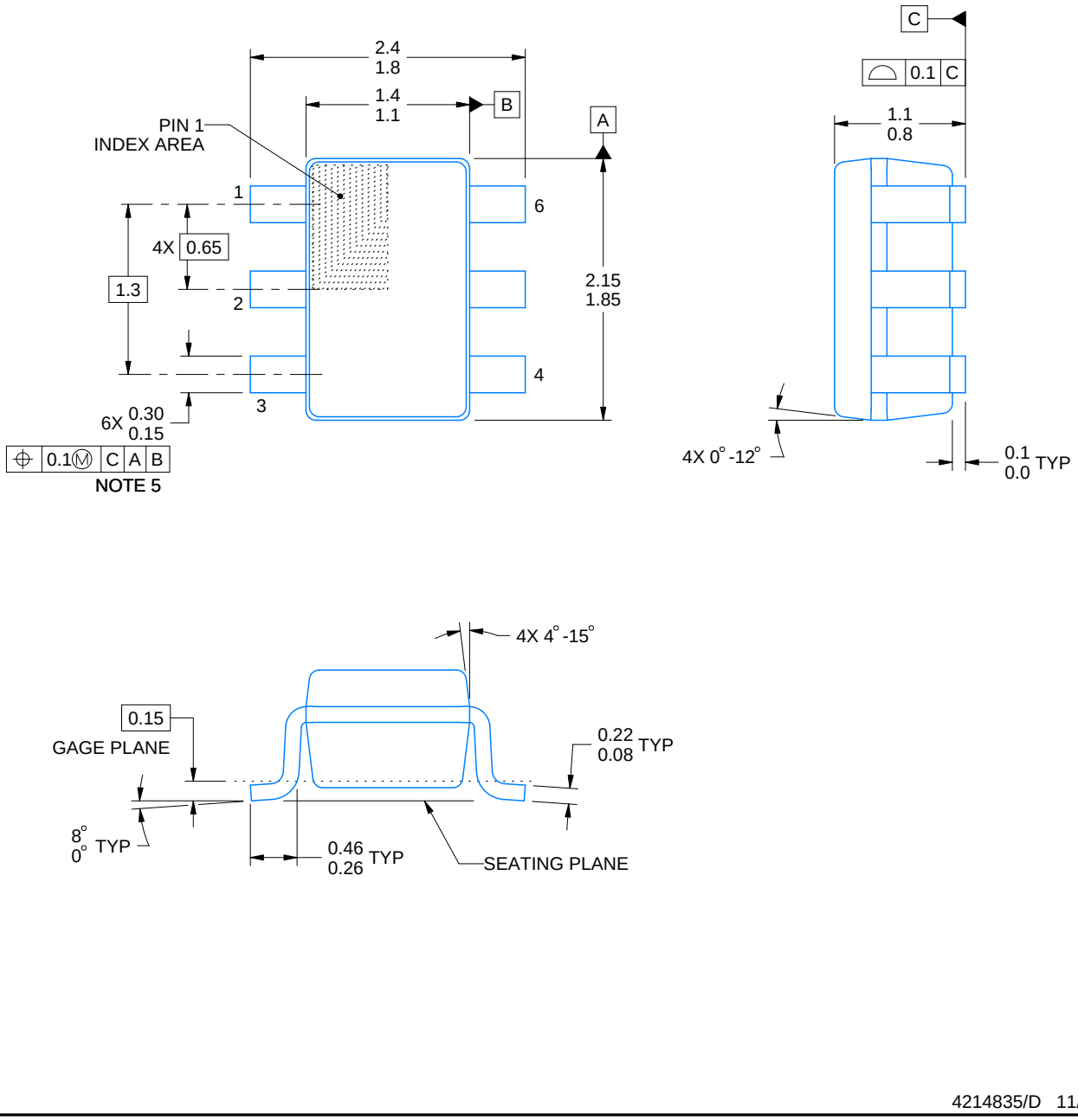
- Catalog - TI's standard catalog product

PACKAGE OUTLINE

DCK0006A

SOT - 1.1 max height

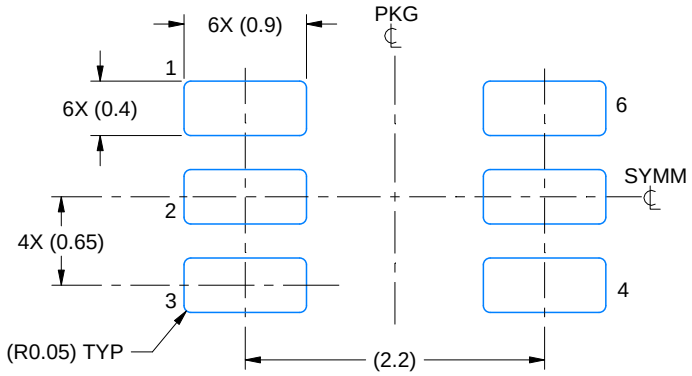
SMALL OUTLINE TRANSISTOR



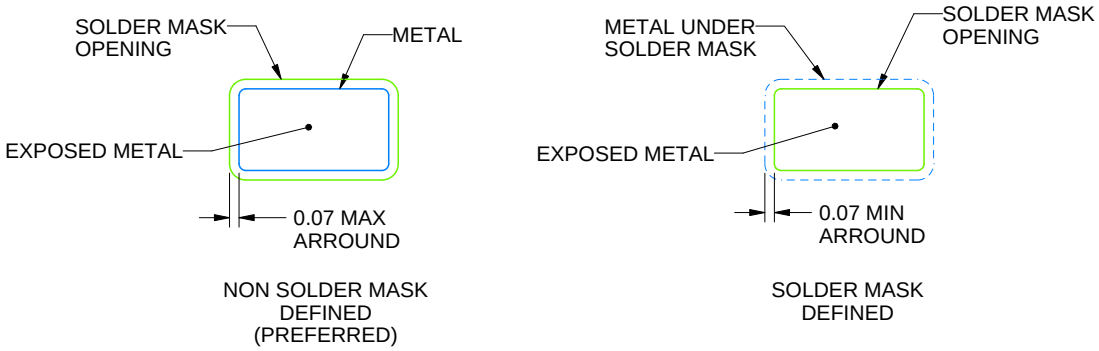
4214835/D 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

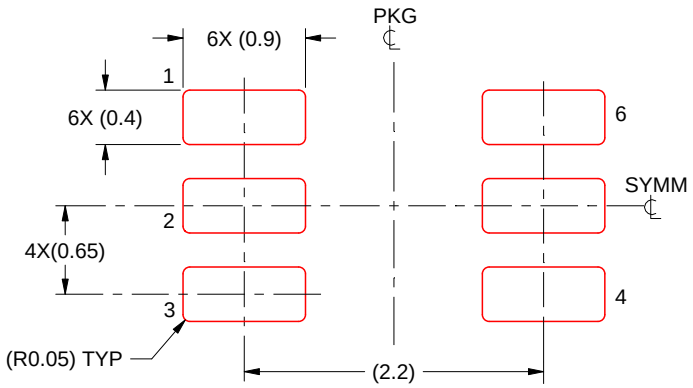


SOLDER MASK DETAILS

4214835/D 11/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

DRY 6 USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



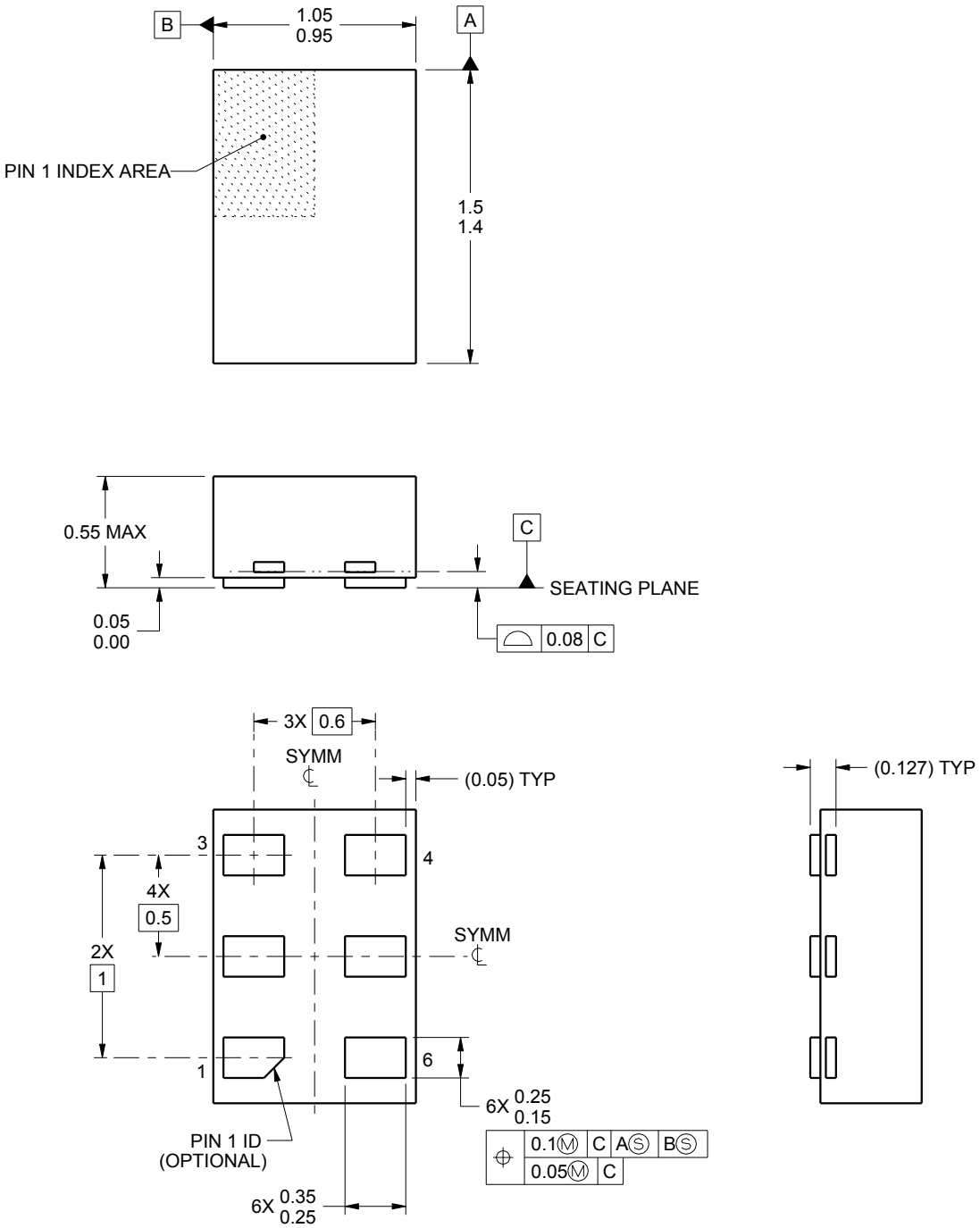
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

PACKAGE OUTLINE

DRY0006B

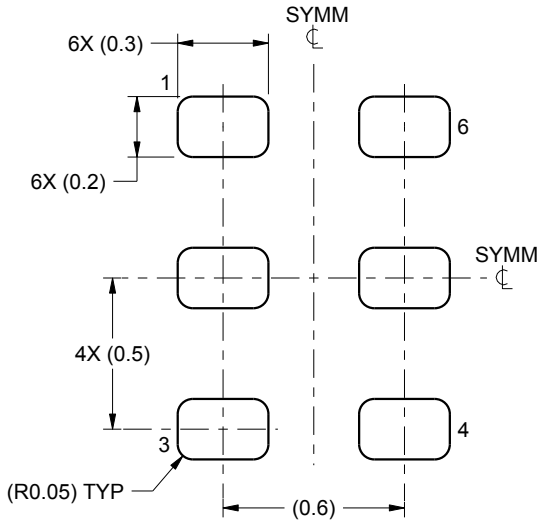
USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

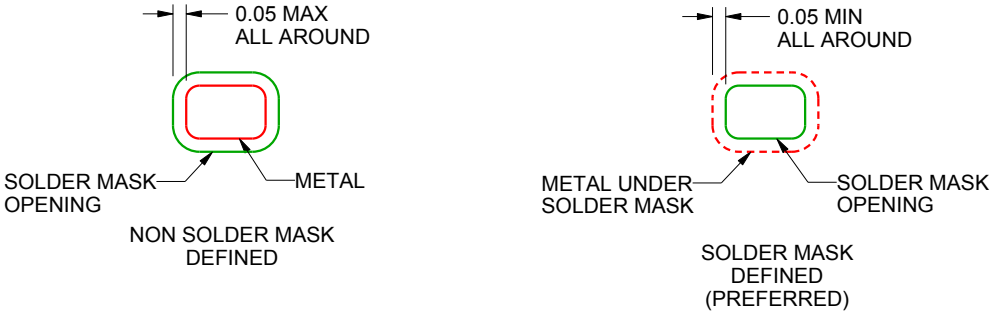


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE
1:1 RATIO WITH PKG SOLDER PADS
SCALE:40X



SOLDER MASK DETAILS

4222207/B 02/2016

NOTES: (continued)

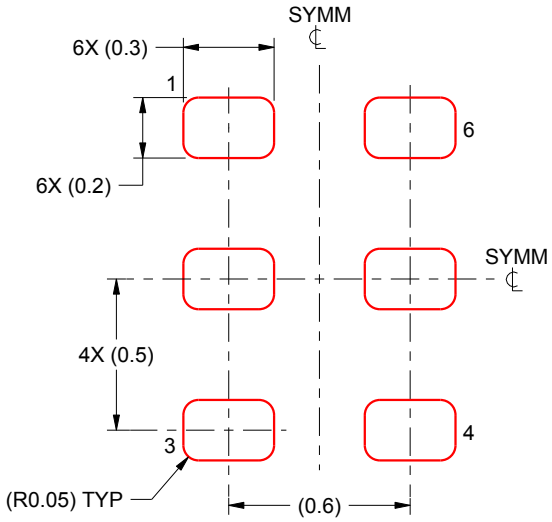
3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

DRY0006B

USON - 0.55 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1 mm THICK STENCIL
SCALE:40X

4222207/B 02/2016

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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最后更新日期：2025 年 10 月